

To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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NPN SILICON RF TRANSISTOR

2SC5754

NPN SILICON RF TRANSISTOR FOR MEDIUM OUTPUT POWER AMPLIFICATION (0.4 W) FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04)

FEATURES

- Ideal for 460 MHz to 2.4 GHz medium output power amplification
- $P_{O(1\text{ dB})} = 26.0\text{ dBm TYP. @ } V_{CE} = 3.6\text{ V, } f = 1.8\text{ GHz, } P_{in} = 15\text{ dBm}$
- High collector efficiency: $\eta_C = 60\%$
- UHSO-HV technology ($f_T = 25\text{ GHz}$) adopted
- High reliability through use of gold electrodes
- Flat-lead 4-pin thin-type super minimold (M04) package

ORDERING INFORMATION

Part Number	Quantity	Supplying Form
2SC5754	50 pcs (Non reel)	• 8 mm wide embossed taping
2SC5754-T2	3 kpcs/reel	• Pin 1 (Emitter), Pin 2 (Collector) face the perforation side of the tape

Remark To order evaluation samples, contact your nearby sales office.
The unit sample quantity is 50 pcs.

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

ABSOLUTE MAXIMUM RATINGS ($T_A = +25^{\circ}\text{C}$)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	V_{CBO}	13	V
Collector to Emitter Voltage	V_{CEO}	5.0	V
Emitter to Base Voltage	V_{EBO}	1.5	V
Collector Current	I_C	500	mA
Total Power Dissipation	P_{tot} ^{Note}	735	mW
Junction Temperature	T_j	150	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	-65 to +150	$^{\circ}\text{C}$

Note Mounted on 38×38 mm, $t = 0.4$ mm polyimide PCB

THERMAL RESISTANCE

	Parameter	Symbol	Test Conditions	Ratings	Unit
★	Junction to Ambient Resistance	$R_{th\ j-a1}$	Mounted on 38×38 mm, $t = 0.4$ mm polyimide PCB	170	$^{\circ}\text{C/W}$
		$R_{th\ j-a2}$	Stand alone device in free air	570	$^{\circ}\text{C/W}$

ELECTRICAL CHARACTERISTICS (T_A = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	I _{CBO}	V _{CB} = 5 V, I _E = 0 mA	–	–	1 000	nA
Emitter Cut-off Current	I _{EBO}	V _{BE} = 1 V, I _C = 0 mA	–	–	1 000	nA
DC Current Gain	h _{FE} ^{Note 1}	V _{CE} = 3 V, I _C = 100 mA	40	60	100	–
RF Characteristics						
Gain Bandwidth Product	f _T	V _{CE} = 3 V, I _C = 100 mA, f = 0.5 GHz	16	20	–	GHz
Insertion Power Gain	S _{21e} ²	V _{CE} = 3 V, I _C = 100 mA, f = 2 GHz	5.0	6.5	–	dB
Reverse Transfer Capacitance	C _{re} ^{Note 2}	V _{CB} = 3 V, I _E = 0 mA, f = 1 MHz	–	1.0	1.5	pF
Maximum Available Power Gain	MAG ^{Note 3}	V _{CE} = 3 V, I _C = 100 mA, f = 2 GHz	–	12.0	–	dB
Linear Gain	G _L	V _{CE} = 3.6 V, I _{CQ} = 20 mA, f = 1.8 GHz, P _{in} = 0 dBm, 1/2 Duty	–	12.0	–	dB
Gain 1 dB Compression Output Power	P _O (1 dB)	V _{CE} = 3.6 V, I _{CQ} = 4 mA, f = 1.8 GHz, P _{in} = 15 dBm, 1/2 Duty	–	26.0	–	dBm
Collector Efficiency	η _C	V _{CE} = 3.6 V, I _{CQ} = 4 mA, f = 1.8 GHz, P _{in} = 15 dBm, 1/2 Duty	–	60	–	%

Notes 1. Pulse measurement: PW ≤ 350 μs, Duty Cycle ≤ 2%

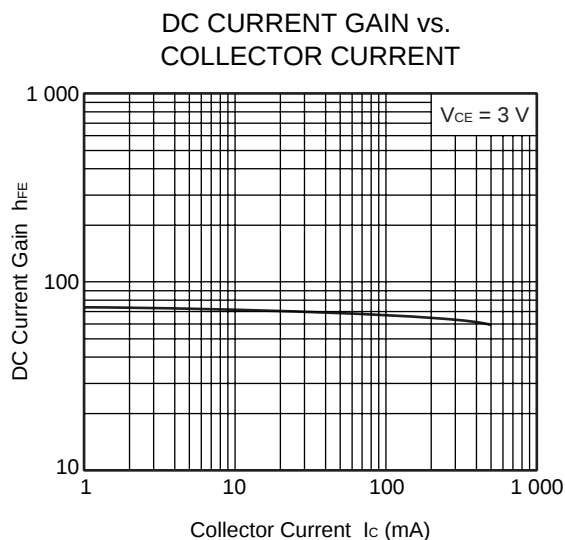
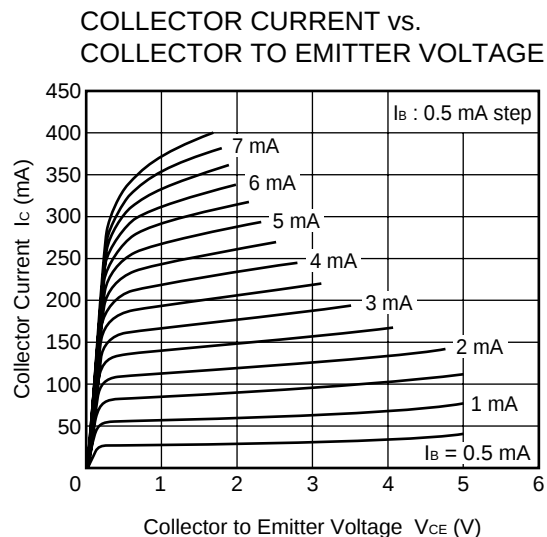
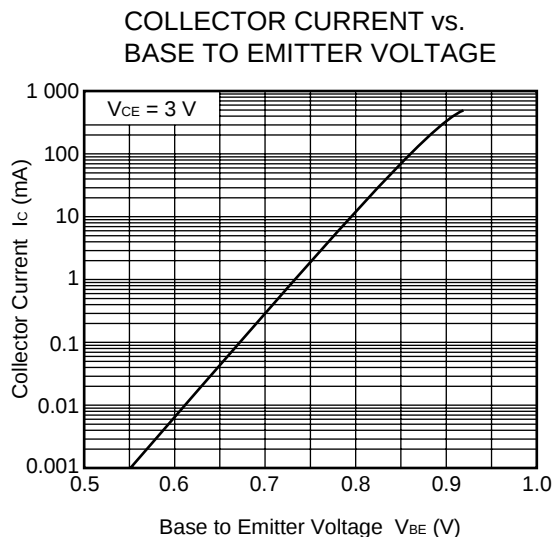
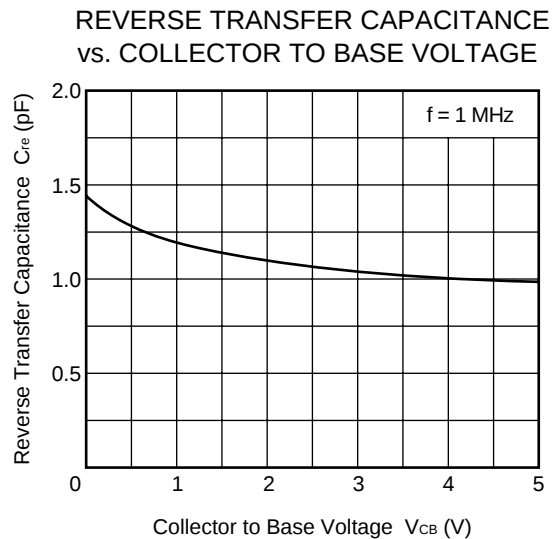
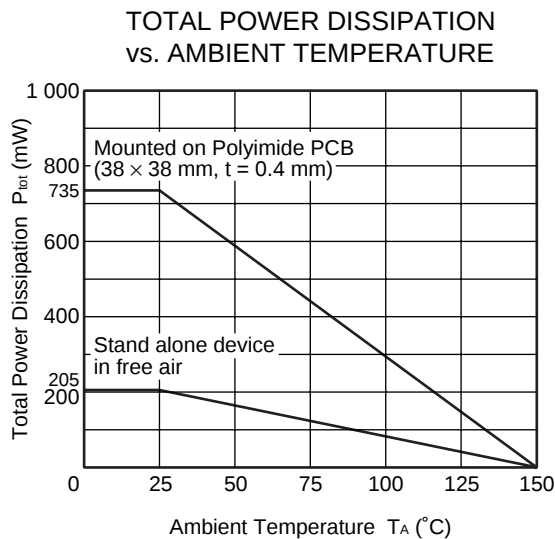
2. Collector to base capacitance when the emitter grounded

$$3. \text{ MAG} = \left| \frac{S_{21}}{S_{12}} \right| (K - \sqrt{K^2 - 1})$$

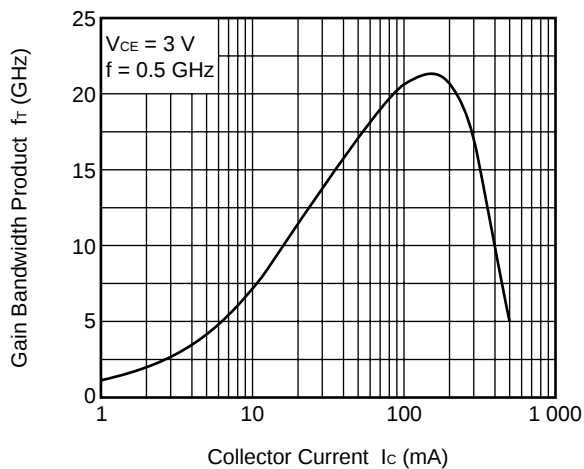
h_{FE} CLASSIFICATION

Rank	FB
Marking	R57
h _{FE} Value	40 to 100

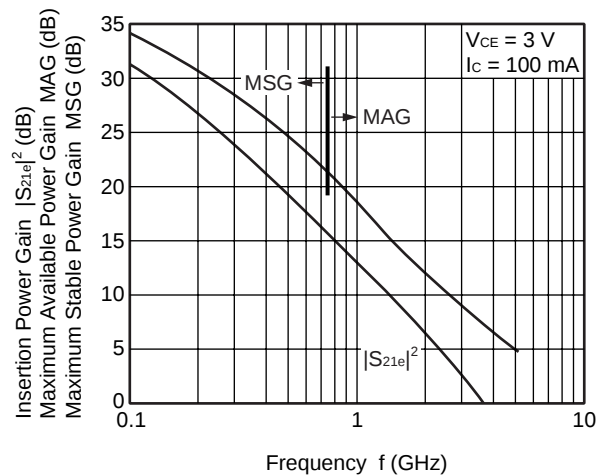
TYPICAL CHARACTERISTICS (Unless otherwise specified, $T_A = +25^\circ\text{C}$)



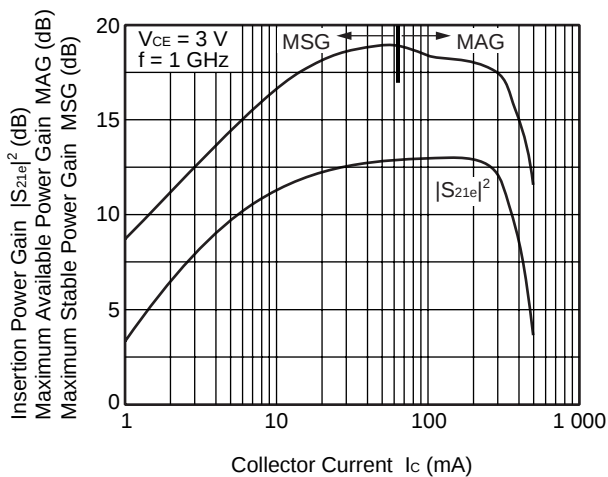
GAIN BANDWIDTH PRODUCT
vs. COLLECTOR CURRENT



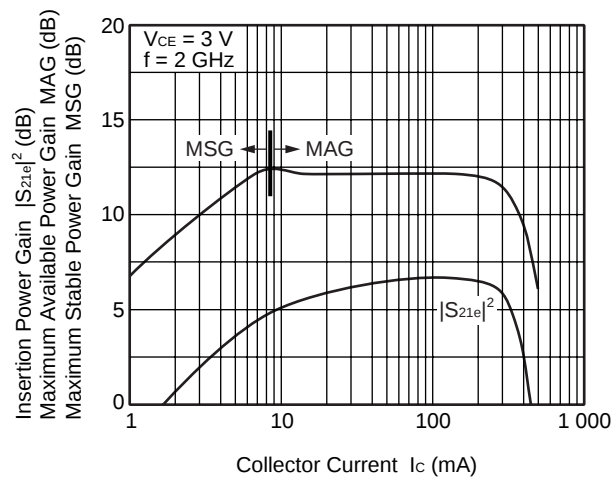
INSERTION POWER GAIN,
MAG, MSG vs. FREQUENCY



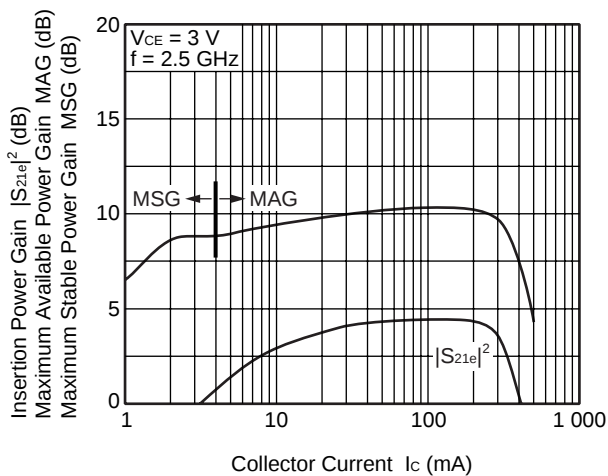
INSERTION POWER GAIN, MAG, MSG
vs. COLLECTOR CURRENT



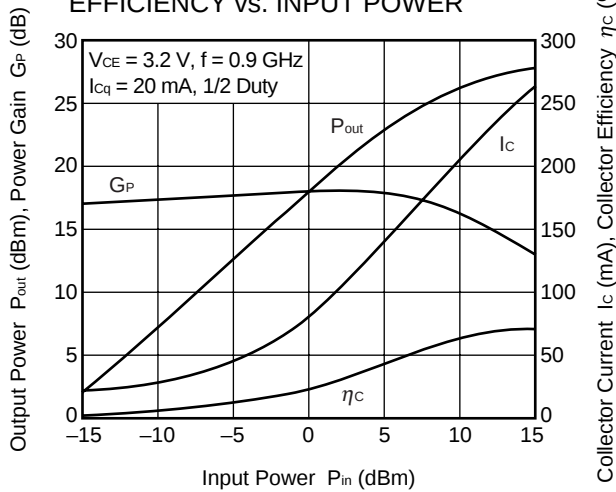
INSERTION POWER GAIN, MAG, MSG
vs. COLLECTOR CURRENT



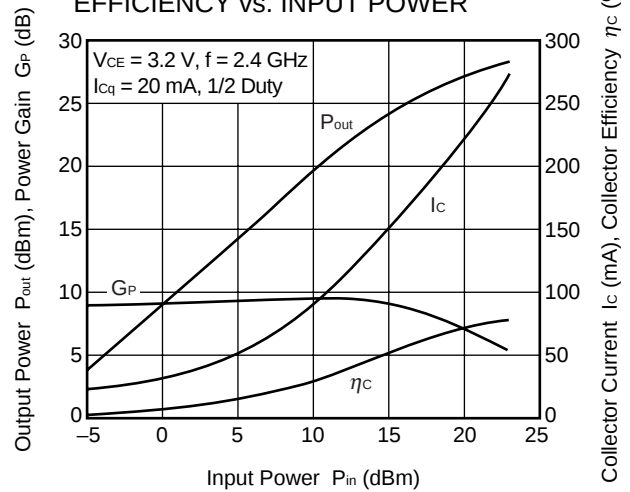
INSERTION POWER GAIN, MAG, MSG
vs. COLLECTOR CURRENT



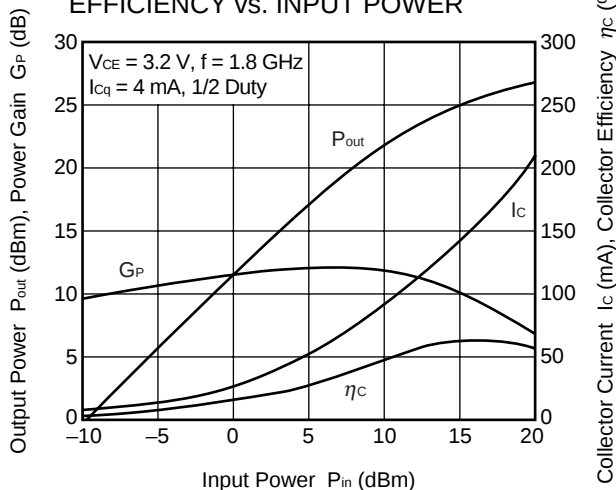
OUTPUT POWER, POWER GAIN,
COLLECTOR CURRENT, COLLECTOR
EFFICIENCY vs. INPUT POWER



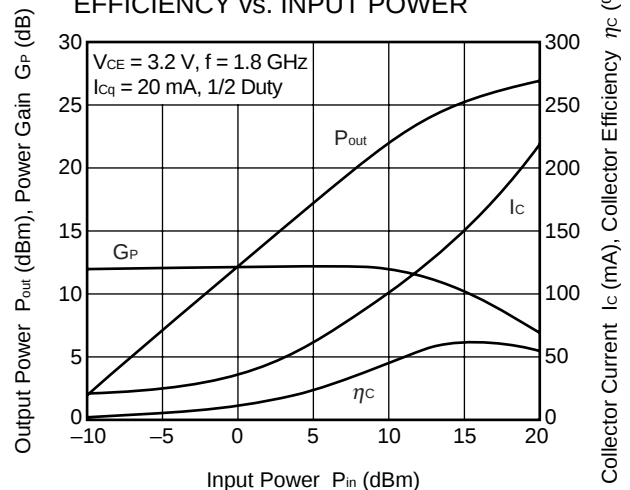
OUTPUT POWER, POWER GAIN,
COLLECTOR CURRENT, COLLECTOR
EFFICIENCY vs. INPUT POWER



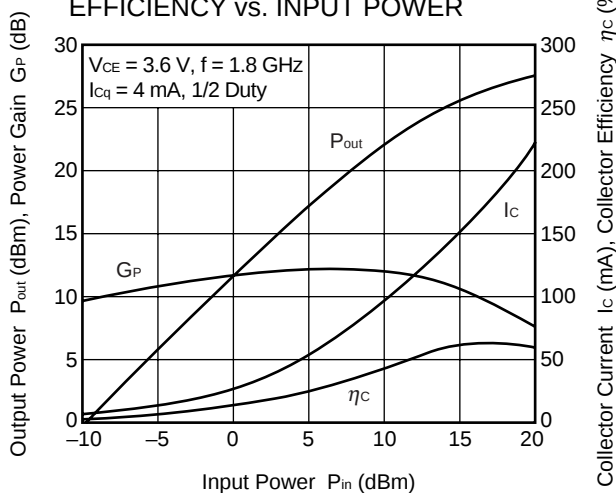
OUTPUT POWER, POWER GAIN,
COLLECTOR CURRENT, COLLECTOR
EFFICIENCY vs. INPUT POWER



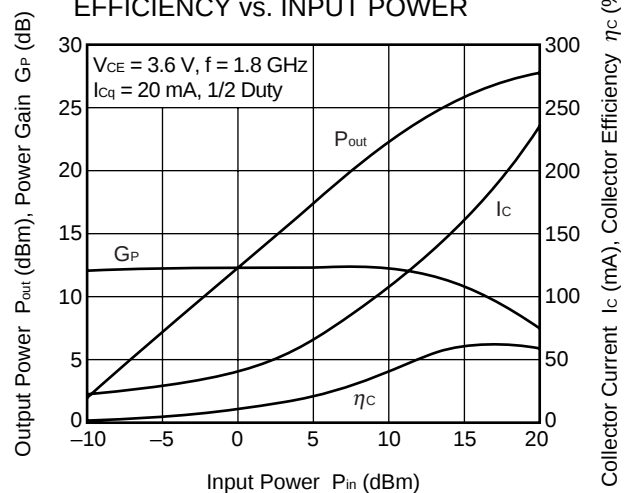
OUTPUT POWER, POWER GAIN,
COLLECTOR CURRENT, COLLECTOR
EFFICIENCY vs. INPUT POWER



OUTPUT POWER, POWER GAIN,
COLLECTOR CURRENT, COLLECTOR
EFFICIENCY vs. INPUT POWER



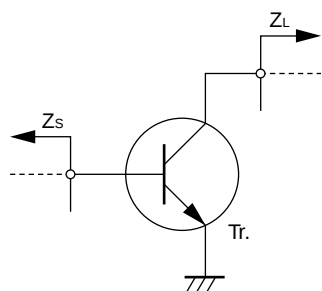
OUTPUT POWER, POWER GAIN,
COLLECTOR CURRENT, COLLECTOR
EFFICIENCY vs. INPUT POWER



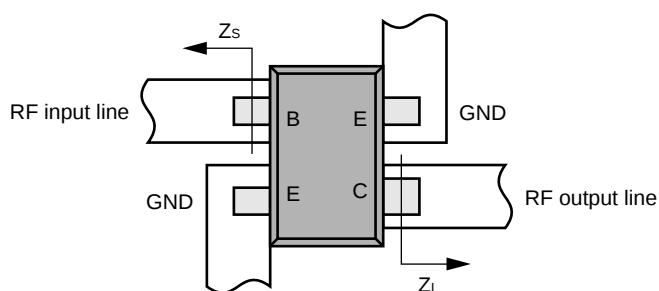
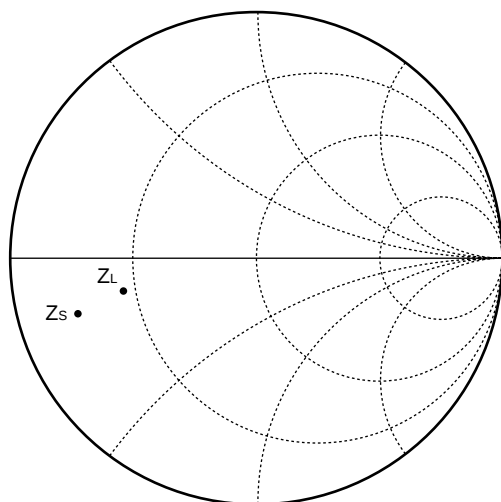
Remark The graphs indicate nominal characteristics.

POWER SUPPLY IMPEDANCE, LOAD IMPEDANCE (Recommended value)

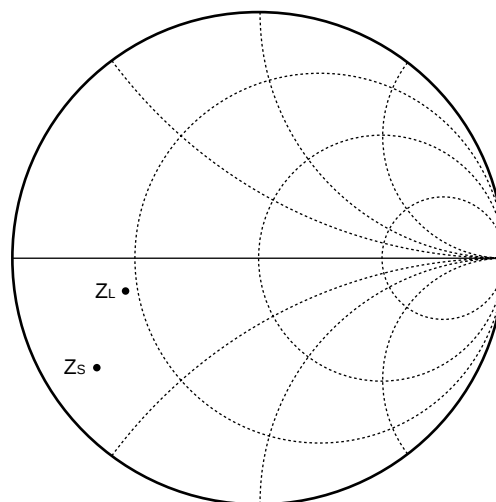
Frequency f (GHz)	Collector to Emitter Voltage V _{CE} (V)	Supply Impedance Z _s (Ω)	Load Impedance Z _L (Ω)
0.9	2.8 to 3.6	8.4 – 5.2 j	15.1 – 4.3 j
1.8	2.8 to 3.6	6.3 – 16.4 j	15.8 – 6.9 j
2.4	2.8 to 3.6	5.9 – 22.1 j	15.2 – 17.9 j



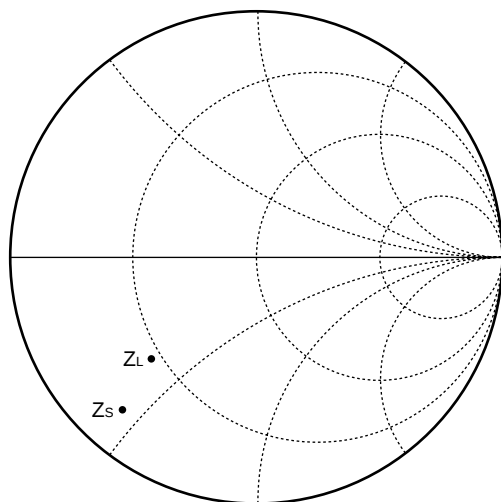
f = 0.9 GHz



f = 1.8 GHz

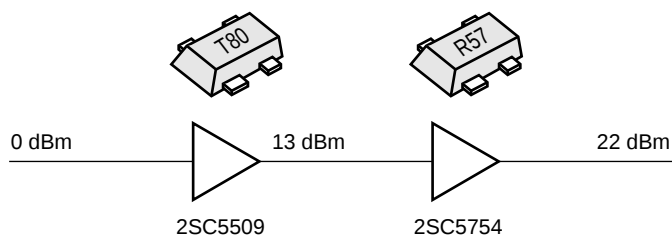


f = 2.4 GHz

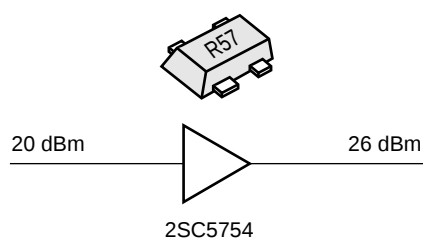


APPLICATION EXAMPLE (Low-cost PA solution)

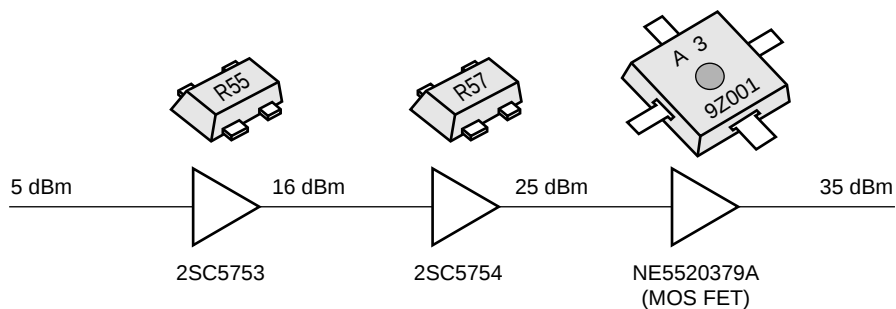
Bluetooth Power Class 1
f = 2.4 GHz



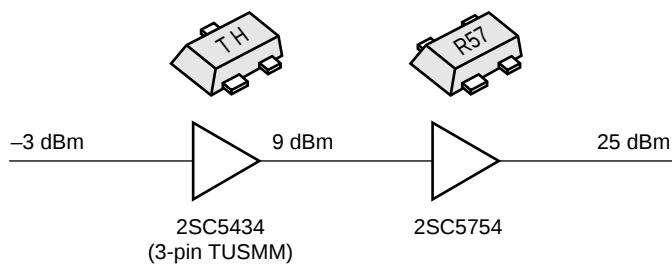
SS Cordless Phone
f = 2.4 GHz



DCS1800 (GSM1800) Cellular Phone
f = 1.8 GHz

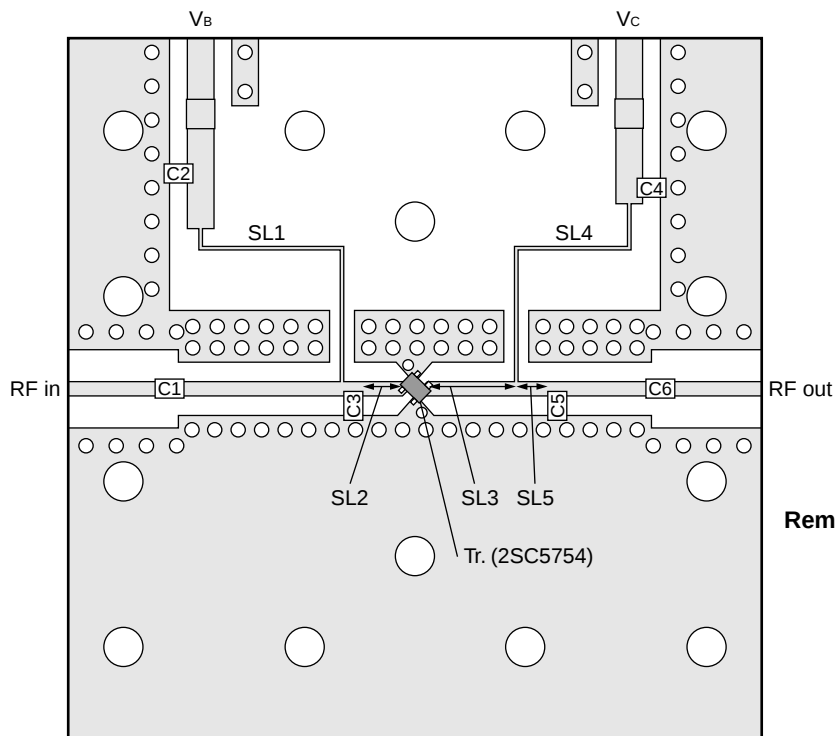


Cordless Phone
f = 0.9 GHz



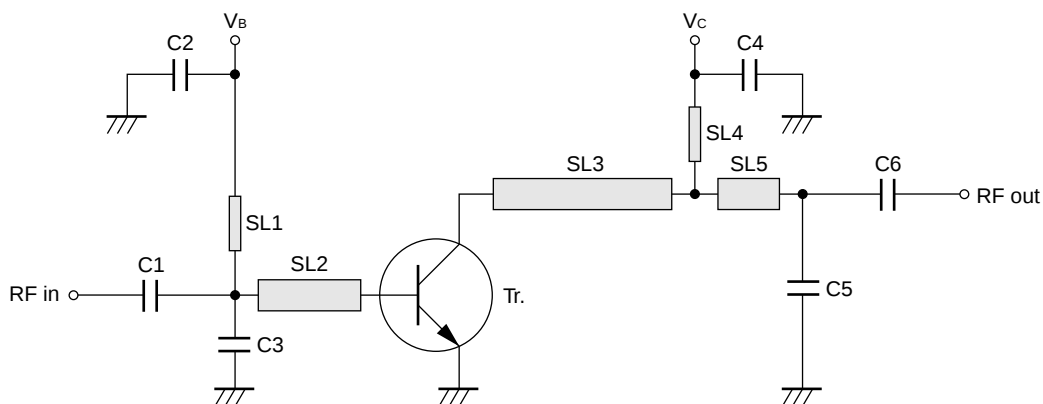
EVALUATION CIRCUIT EXAMPLE : 1.8 GHz PA EVALUATION BOARD

PCB Pattern and Element Layout



- Remarks**
1. 38 × 38 mm, t = 0.4 mm, $\epsilon_r = 4.55$ double-sided copper-clad polyimide board
 2. Back side : GND pattern
 3. Solder plating on pattern
 4. ○○ : Through holes

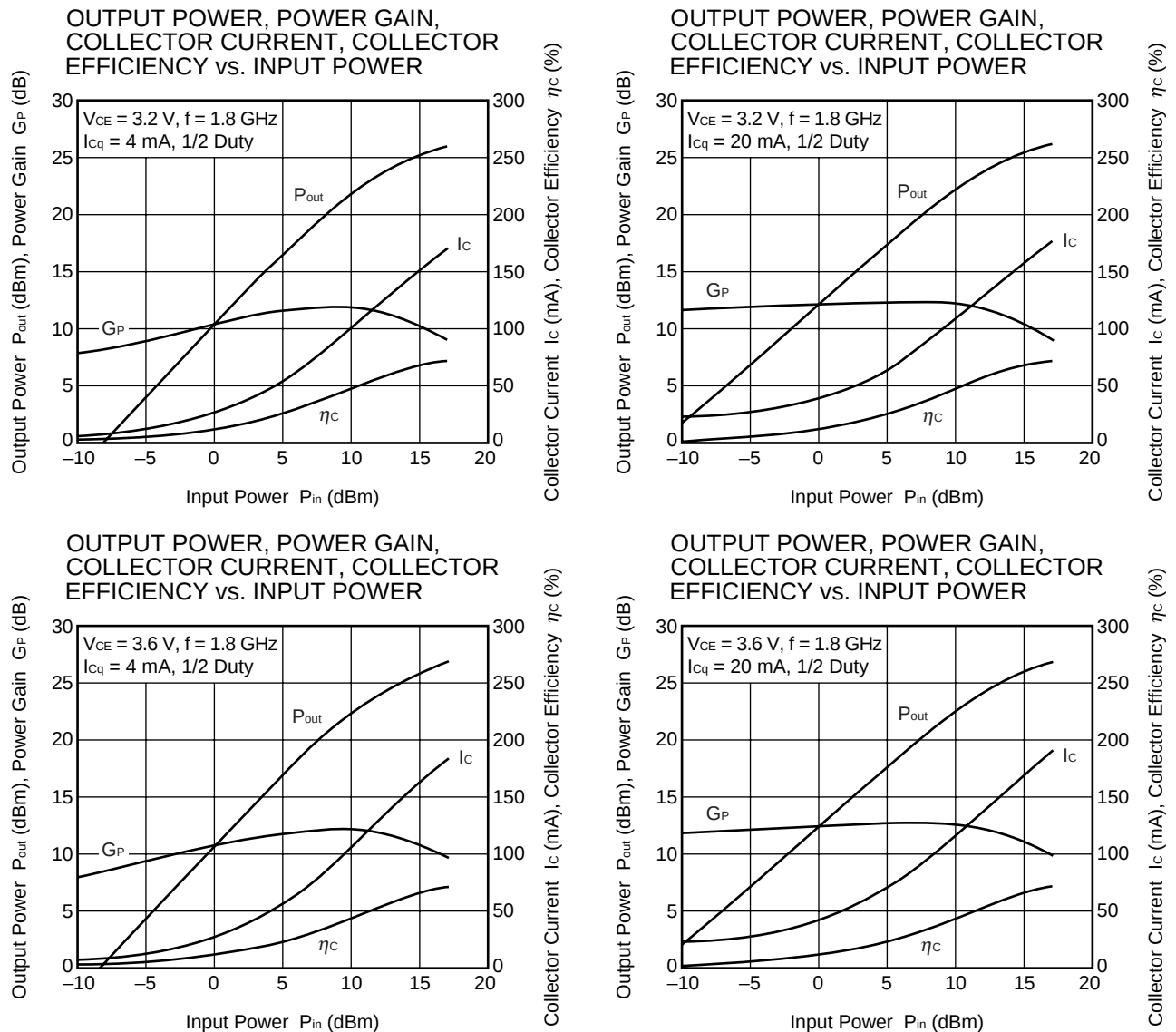
Equivalent Circuit



Parts List

Parts	Value	Size	Classification
C1, C6	18 pF		Multiplayer ceramic chip capacitor
C2	3 300 pF		Multiplayer ceramic chip capacitor
C3	3 pF		Multiplayer ceramic chip capacitor
C4	15 pF		Multiplayer ceramic chip capacitor
C5	1.5 pF		Multiplayer ceramic chip capacitor
SL1, SL4		w = 0.20 mm	Strip line
SL2		w = 0.76 mm, l = 2.5 mm	Strip line
SL3		w = 0.76 mm, l = 5 mm	Strip line
SL5		w = 0.76 mm, l = 1.5 mm	Strip line

EXAMPLE OF CHARACTERISTICS FOR 1.8 GHz PA EVALUATION BOARD



Remark The graphs indicate nominal characteristics.

S-PARAMETERS

S-parameters/Noise parameters are provided on the NEC Compound Semiconductor Devices Web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.

Click here to download S-parameters.

[RF and Microwave] → [Device Parameters]

URL <http://www.csd-nec.com/>

FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04) (UNIT: mm)



1. Emitter
2. Collector
3. Emitter
4. Base

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